

RSD221N06FRA

Nch 60V 22A Power MOSFET

| V_{DSS} | 60V |
|----------------------------|------|
| R _{DS(on)} (Max.) | 26mΩ |
| I _D | ±22A |
| P_D | 20W |

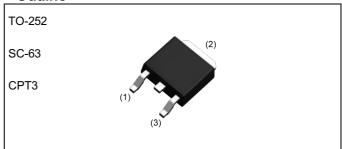
Features

- 1) Low on resistance.
- 2) Fast switching speed.
- 3) Drive circuits can be simple.
- 4) Parallel use is easy.
- 5) Pb-free lead plating; RoHS compliant
- 6) AEC-Q101 Qualified

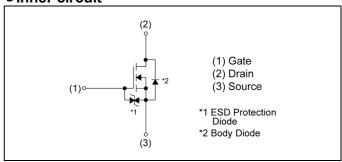
Application

Switching

Outline



•Inner circuit



Packaging specifications

| | Packing | Embossed Tape |
|------|---------------------------|------------------|
| | Reel size (mm) | 330 |
| Туре | Tape width (mm) | 16 |
| | Basic ordering unit (pcs) | 2500 |
| | Taping code | TL |
| | Marking | 221N06 |

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

| Parameter | Symbol | Value | Unit |
|--|--------------------|-------------|------|
| Drain - Source voltage | V _{DSS} | 60 | V |
| Continuous drain current | I _D *1 | ±22 | Α |
| Pulsed drain current | I _{DP} *2 | ±44 | Α |
| Gate - Source voltage | V _{GSS} | ±20 | V |
| Power dissipation | P _D *3 | 20 | W |
| Junction temperature | T _j | 150 | °C |
| Operating junction and storage temperature range | T _{stg} | -55 to +150 | °C |

●Thermal resistance

| Doromotor | Cymbol | Values | | | l leit |
|-------------------------------------|----------------------|--------|------|------|--------|
| Parameter | Symbol | Min. | Тур. | Max. | Unit |
| Thermal resistance, junction - case | R _{thJC} *3 | - | - | 6.25 | °C/W |

● Electrical characteristics (T_a = 25°C)

| Parameter | Symbol | Conditions | | | Values | | |
|--|---|--|------|------|--------|-------|--|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit | |
| Drain - Source breakdown voltage | V _{(BR)DSS} | $V_{GS} = 0V$, $I_D = 1mA$ | 60 | - | - | V | |
| Breakdown voltage temperature coefficient | $\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$ | I _D = 1mA referenced to 25°C | - | 63.7 | - | mV/°C | |
| Zero gate voltage drain current | I _{DSS} | V _{DS} = 60V, V _{GS} = 0V | - | - | 1 | μA | |
| Gate - Source leakage current | I _{GSS} | $V_{GS} = \pm 20V$, $V_{DS} = 0V$ | - | - | ±10 | μA | |
| Gate threshold voltage | $V_{GS(th)}$ | V _{DS} = 10V , I _D = 1mA | 1.0 | - | 3.0 | V | |
| Gate threshold voltage temperature coefficient | $\frac{\Delta V_{GS(th)}}{\Delta T_{j}}$ | I _D = 1mA referenced to 25°C | - | -2.8 | - | mV/°C | |
| | | V _{GS} = 10V, I _D = 22A | - | 18 | 26 | | |
| Static drain - source on - state resistance | R _{DS(on)} *4 | $V_{GS} = 4.5V, I_D = 22A$ | - | 21 | 30 | mΩ | |
| | | $V_{GS} = 4.0V, I_D = 22A$ | - | 23 | 33 | | |
| Gate resistance | R_{G} | f = 1MHz, open drain | - | 5.0 | 1 | Ω | |
| Forward Transfer Admittance | Y _{fs} *4 | V _{DS} = 10V, I _D = 22A | 12 | - | - | S | |

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw \leq 10 μ s , Duty cycle \leq 1%

^{*3} T_C=25°C

^{*4} Pulsed

●Electrical characteristics (T_a = 25°C)

| Daramatar | Cymahal | Conditions | Values | | | Unit |
|------------------------------|------------------------|-----------------------------------|--------|------|------|------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit |
| Input capacitance | C _{iss} | V _{GS} = 0V | - | 1500 | - | _ |
| Output capacitance | C _{oss} | V _{DS} = 10V | - | 320 | - | pF |
| Reverse transfer capacitance | C _{rss} | f = 1MHz | - | 140 | - | |
| Turn - on delay time | t _{d(on)} *4 | $V_{DD} \simeq 30V, V_{GS} = 10V$ | - | 25 | - | |
| Rise time | t _r *4 | I _D = 11A | - | 45 | - | no |
| Turn - off delay time | t _{d(off)} *4 | $R_L \simeq 2.7\Omega$ | - | 75 | - | ns |
| Fall time | t _f *4 | $R_G = 10\Omega$ | - | 65 | - | |

● Gate charge characteristics (T_a = 25°C)

| 3 · · · · · · · · · · · · · · · · · · · | | | | | | | | |
|---|--------------------|------------------------|--------|------|------|--------|--|--|
| Darameter | Cymab al | Conditions | Values | | | 1.1-:4 | | |
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit | | |
| Total gate charge | Qg*4 | V _{DD} ≃ 30V, | - | 30 | - | | | |
| Gate - Source charge | Q _{gs} *4 | I _D = 22A, | - | 4.5 | - | nC | | |
| Gate - Drain charge | Q _{gd} *4 | V _{GS} = 10V | - | 3.0 | - | | | |

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

| Darameter | Symbol | Conditions | Values | | | Unit |
|----------------------------|--------------------|--|--------|------|------|-------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Offic |
| Continuous forward current | I _S *1 | T = 25°C | - | - | 16 | Α |
| Pulse forward current | I _{SP} *2 | T _a = 25℃ | - | - | 44 | Α |
| Forward voltage | V _{SD} *4 | V _{GS} = 0V, I _S = 22A | - | - | 1.2 | V |

Fig.1 Power Dissipation Derating Curve

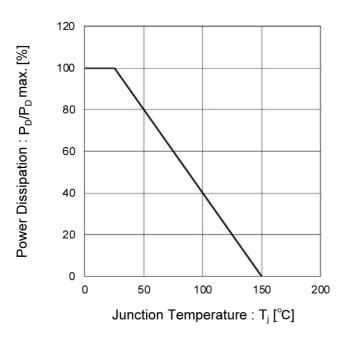


Fig.2 Maximum Safe Operating Area

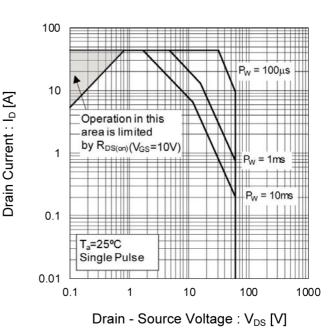


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

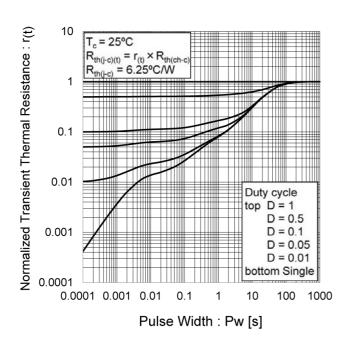
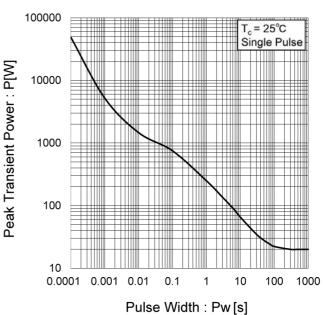


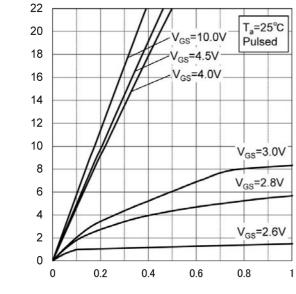
Fig.4 Single Pulse Maximum Power dissipation



Drain Current : I_D [A]

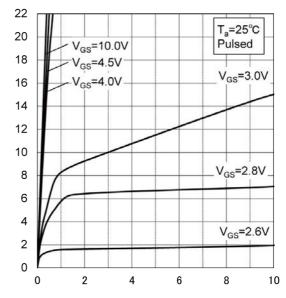
• Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)



Drain - Source Voltage: V_{DS} [V]

Fig.6 Typical Output Characteristics(II)



Drain Current : I_D [A]

Drain - Source Voltage : V_{DS} [V]

Fig.7 Breakdown Voltage vs.
Junction Temperature

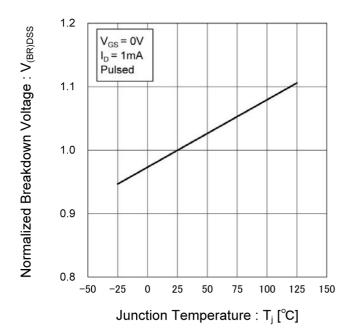


Fig.8 Typical Transfer Characteristics

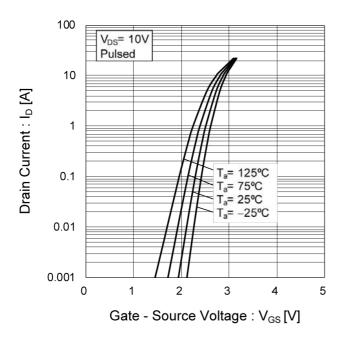


Fig.9 Gate Threshold Voltage vs.

Junction Temperature

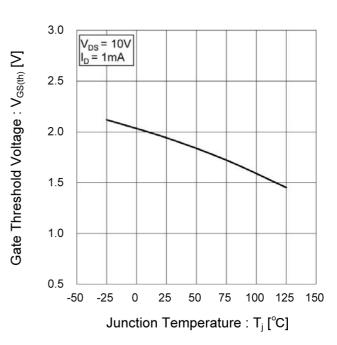


Fig.10 Forward Transfer Admittance vs.
Drain Current

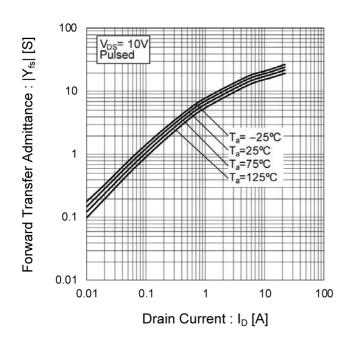


Fig.11 Drain Current Derating Curve

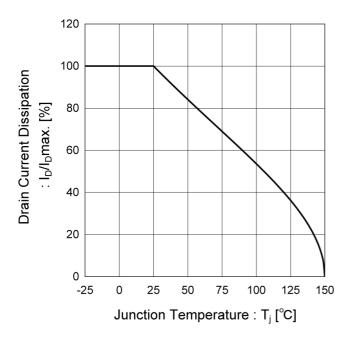


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

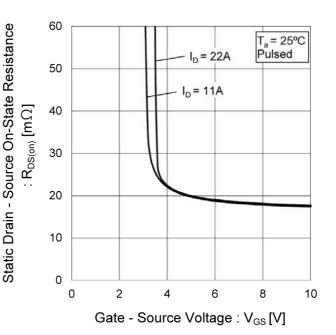
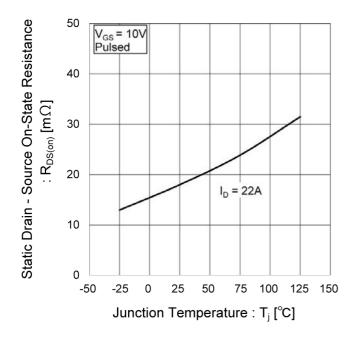


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature



RSD221N06FRA

Fig.14 Static Drain - Source On - State Resistance vs. Drain Current(I)

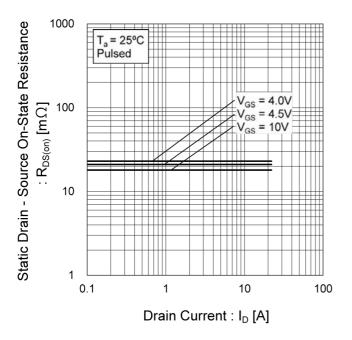


Fig.15 Static Drain - Source On - State
Resistance vs. Drain Current(II)

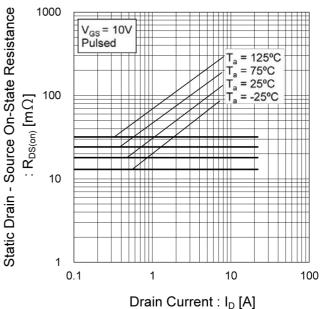


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)

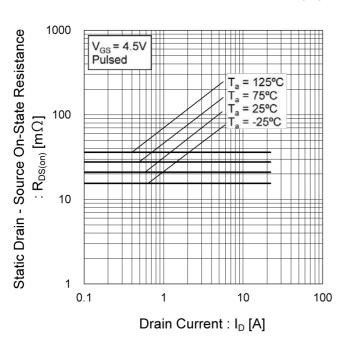


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current(IV)

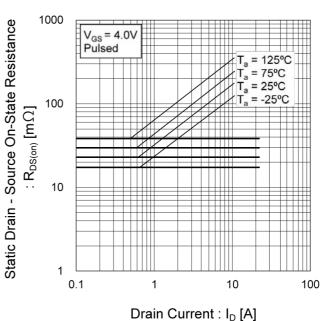


Fig.18 Typical Capacitance vs.

Drain - Source Voltage

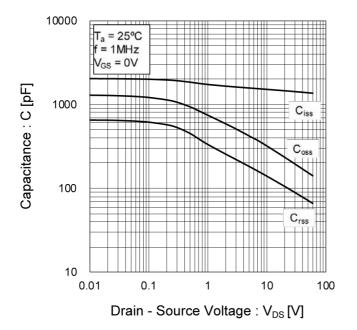


Fig.19 Switching Characteristics

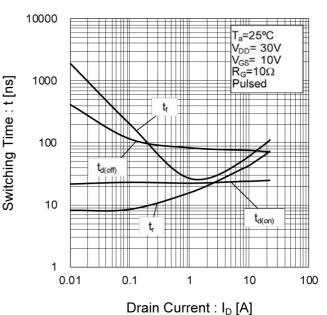


Fig.20 Dynamic Input Characteristics

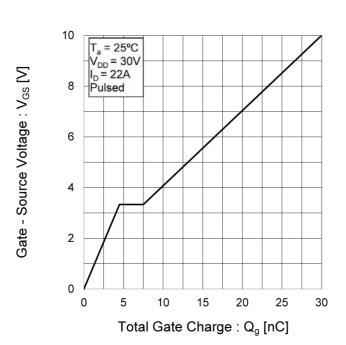
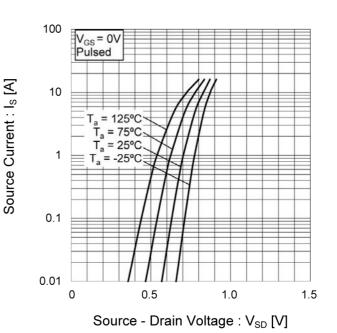


Fig.21 Source Current vs.

Source Drain Voltage



9/11

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

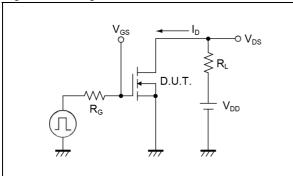


Fig.2-1 Gate Charge Measurement Circuit

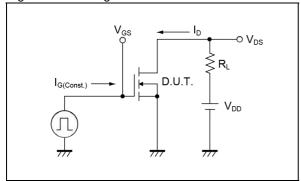


Fig.1-2 Switching Waveforms

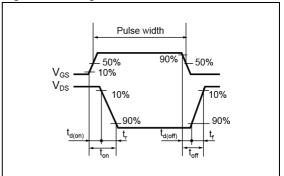
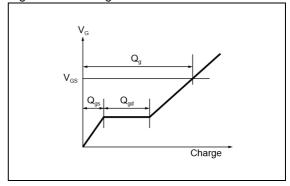
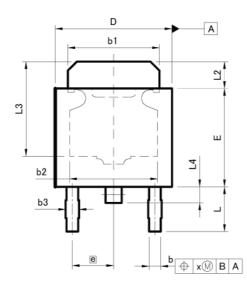


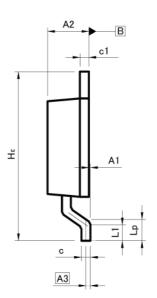
Fig.2-2 Gate Charge Waveform

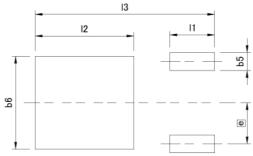


Dimensions









Pattern of terminal position areas [Not a pattern of soldering pads]

| DIM | MILIM | MILIMETERS | | HES |
|--------|-------|------------|----------|-------|
| 75,000 | MIN | MAX | MIN | MAX |
| A1 | 0.00 | 0.15 | 0.000 | 0.006 |
| A2 | 2.20 | 2.50 | 0.087 | 0.098 |
| A3 | 0. | 25 | 0.0 | 10 |
| b | 0.55 | 0.75 | 0.022 | 0.030 |
| b1 | 5.00 | 5.30 | 0.197 | 0.209 |
| b2 | | 90 | 0.1 | |
| b3 | | 75 | | 30 |
| С | 0.40 | 0.60 | 0.016 | 0.024 |
| c1 | 0.40 | 0.60 | 0.016 | 0.024 |
| D | 6.30 | 6.70 | 0.248 | 0.264 |
| E | 5.40 | 5.80 | 0.213 | 0.228 |
| е | 2. | 30 | 0.0 | 91 |
| HE | 9.00 | 10.00 | 0.354 | 0.394 |
| L | 2.20 | 2.80 | 0.087 | 0.110 |
| L1 | 0.80 | 1.40 | 0.031 | 0.055 |
| L2 | 1.20 | 1.80 | 0.047 | 0.071 |
| L3 | 5. | 30 | 0.2 | 09 |
| L4 | 0. | 90 | 0.0 | 35 |
| Lp | 1.00 | 1.60 | 0.039 | 0.063 |
| Х | 7229 | 0.25 | <u> </u> | 0.010 |

| DIM | MILIM | MILIMETERS | | HES |
|-----|-------------------|------------|-------------|-------|
| DIM | MIN | MAX | MIN | MAX |
| b5 | - | 1.00 | | 0.04 |
| b6 | (-1) | 5.20 | | 0.205 |
| 11 | - | 2.50 | - | 0.098 |
| 12 | - | 5.50 | | 0.217 |
| 13 | - | 10.00 | 140 | 0.394 |

Dimension in mm/inches



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| CLASSIV | CLASSIII | CLASSⅢ | CLASSIII |

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 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
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